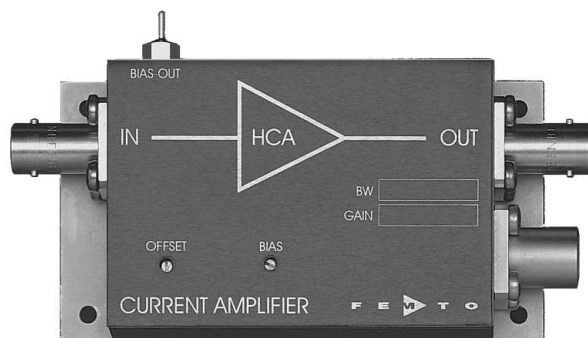


# High-Speed Current Amplifier

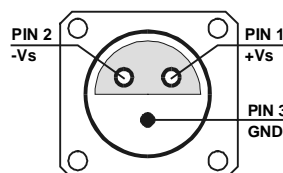


|                    |   |  |
|--------------------|---|--|
| Features           | <ul style="list-style-type: none"> <li>• <b>Bandwidth and Frequency Response independent of Detector-Capacitance (up to 50 pF)</b></li> <li>• <b>Low Noise, 3.5 pA/√Hz equivalent Input Noise Current</b></li> <li>• <b>Bandwidth DC ... 20 MHz</b></li> <li>• <b>Transimpedance (Gain) <math>1 \times 10^5</math> V/A</b></li> <li>• <b>Protection against <math>\pm 3.5</math> kV Transients</b></li> </ul>   |  |
| Applications       | <ul style="list-style-type: none"> <li>• <b>Photodiode- and Photomultiplier-Amplifier</b></li> <li>• <b>Spectroscopy</b></li> <li>• <b>Charge-Amplifier</b></li> <li>• <b>Ionisation Detectors</b></li> <li>• <b>Preamplifier for Lock-Ins, A/D-Converters, etc.</b></li> </ul>   |  |
| Specifications     | <p><i>Test Conditions</i></p> <p><i>Vs = <math>\pm 15</math> V, Ta = 25°C</i></p>   |  |
| Gain               | <p>Transimpedance <math>1 \times 10^5</math> V/A (50 <math>\Omega</math> Load)</p> <p>Gain Accuracy <math>\pm 1</math> %</p>  |  |
| Frequency Response | <p>Lower Cut-Off Frequency DC</p> <p>Upper Cut-Off Frequency 20 MHz (- 3 dB)</p> <p>Rise- / Fall-Time 18 ns (10% - 90%)</p> <p>Gain Flatness <math>\pm 0.3</math> dB</p>  |  |
| Input              | <p>Equ. Input Noise Current 3.5 pA/√Hz (@ 100 kHz)</p> <p>Equ. Input Noise Voltage 0.8 nV/√Hz (@ 100 kHz)</p> <p>Input Bias Current 18 <math>\mu</math>A typ.</p> <p>Input Bias Current Drift 0.8 nA / K</p> <p>Offset Current Compensation <math>\pm 20</math> <math>\mu</math>A, adjustable by Offset-Trimpot</p> <p>Max. Input Current <math>\pm 15</math> <math>\mu</math>A (linear Amplification)</p> <p>Input Offset Voltage &lt; 3 mV</p> <p>DC Input Impedance 50 <math>\Omega</math> (virtual) // 5 pF</p> |  |
| Output             | <p>Output Voltage <math>\pm 1.5</math> V (50 <math>\Omega</math> Load)</p> <p>Output Impedance 50 <math>\Omega</math></p>   |  |
| Bias Output        | <p>Bias Output Voltage Range <math>\pm 12</math> V, adjustable by Bias-Trimpot</p> <p>Bias Output Impedance 10 k<math>\Omega</math> // 1 <math>\mu</math>F</p>  |  |
| Power Supply       | <p>Supply Voltage <math>\pm 15</math> V</p> <p>Supply Current <math>\pm 70</math> mA typ.</p>   |  |
| Case               | <p>Weight 210 gr. (0.5 lbs)</p> <p>Material AlMg4.5Mn, nickel-plated</p>  |  |

## High-Speed Current Amplifier

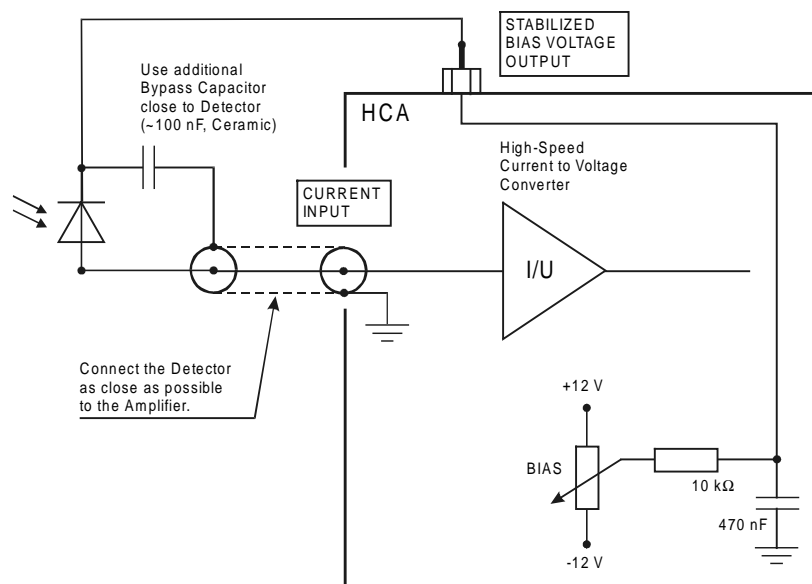
### Specifications (continued)

|                          |                         |  |
|--------------------------|-------------------------|--|
| Temperature Range        | Storage Temperature     | -40 ... +100 °C  |
|                          | Operating Temperature   | 0 ... +60 °C   |
| Absolute Maximum Ratings | Input Voltage           | ± 5 V  |
|                          | Input Voltage Transient | ± 3.5 kV (Pulsewidth 10 ns)  |
|                          | Power Supply Voltage    | ± 22 V   |
| Connectors               | Input                   | BNC  |
|                          | Output                  | BNC  |
|                          | Power Supply            | LEMO Series 1S, 3-pin fixed Socket<br>Pin 1: + 15V<br>Pin 2: - 15V<br>Pin 3: GND |



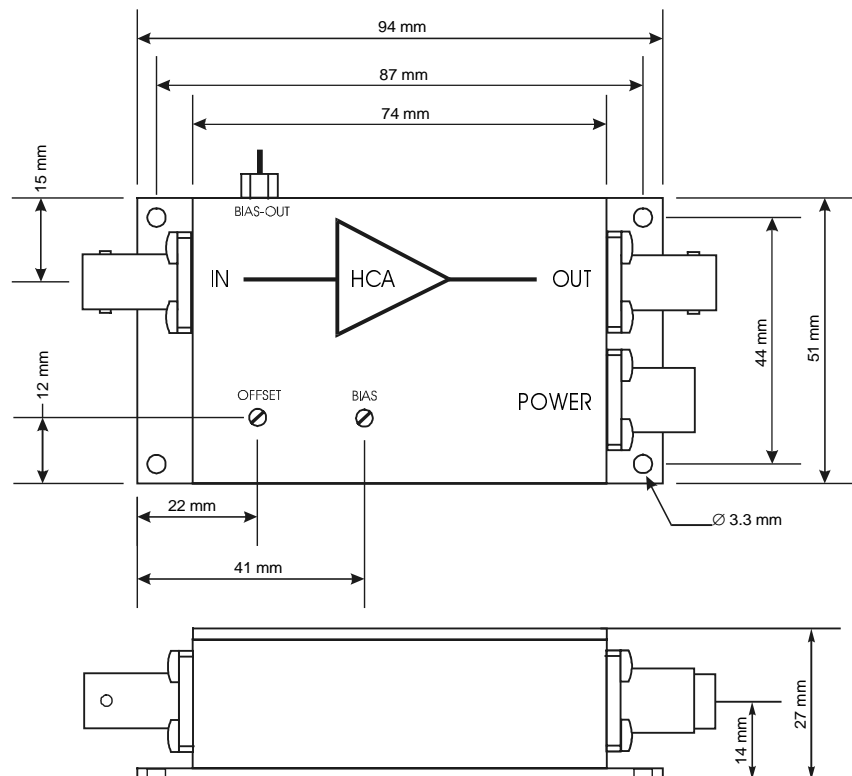
### Application Diagrams

Photo Detector Biasing in Photoconductive Mode:  
Best Choice for High-Speed Applications and  
optimum Signal To Noise Performance.



AZ01-0201-20

## Dimensions



DZ01-0201-22

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